

## Review of physical properties of NASICON materials for use in sodium batteries

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The structure, compositional diversity and ionic conductivity of Na<sup>+</sup> ion-conducting NASICON materials are reviewed in order to correlate the lattice parameters and specific crystal structure data with the sodium mobility and the activation energy.

## **Correlation structure / ionic conductivity:**

General formula of a sodium NASICON material:

$$Na_{1+2x+y}M^{II}_{x}M^{III}_{y}M^{IV}_{2-x-y}(SiO_{4})_{z}(PO_{4})_{3-z}$$

Extensive study for approximately 150 compositions:

Introduction of a geometrical parameter: the effective ionic radius r<sub>eff</sub>

$$r_{eff} = \frac{x \times r_{M^{II}} + y \times r_{M^{III}} + (2 - x - y) \times r_{M^{IV}}}{2}$$

- Illustration of an optimal size for M<sup>II</sup>, M<sup>III</sup> and M<sup>IV</sup>,  $r_{eff} \approx r_{ZrIV} = 0.72 \text{ Å}$
- Impact of the amount of Na per formula on the conductivity.
- Importance of the substitution of P with Si

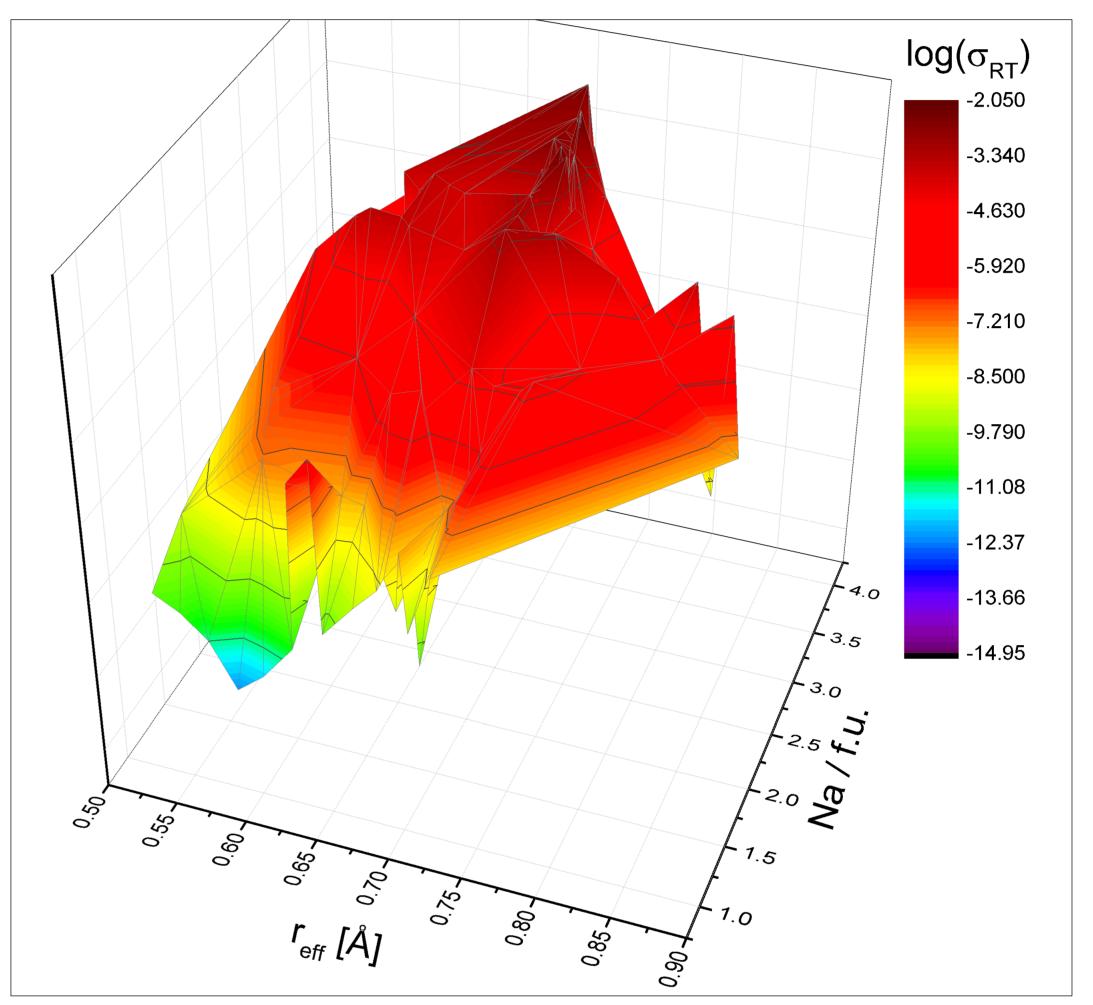


Figure 1:  $log(\sigma_{RT})$  as a function of the Na content per formula and the effective ionic radius of the cations in  $Na_{1+2x+y}M^{II}_{x}M^{III}_{y}M^{IV}_{2-x-y}(SiO_{4})_{z}(PO_{4})_{3-z}$ .

## Bottleneck for Na+ conduction, correlation with the activation energy:

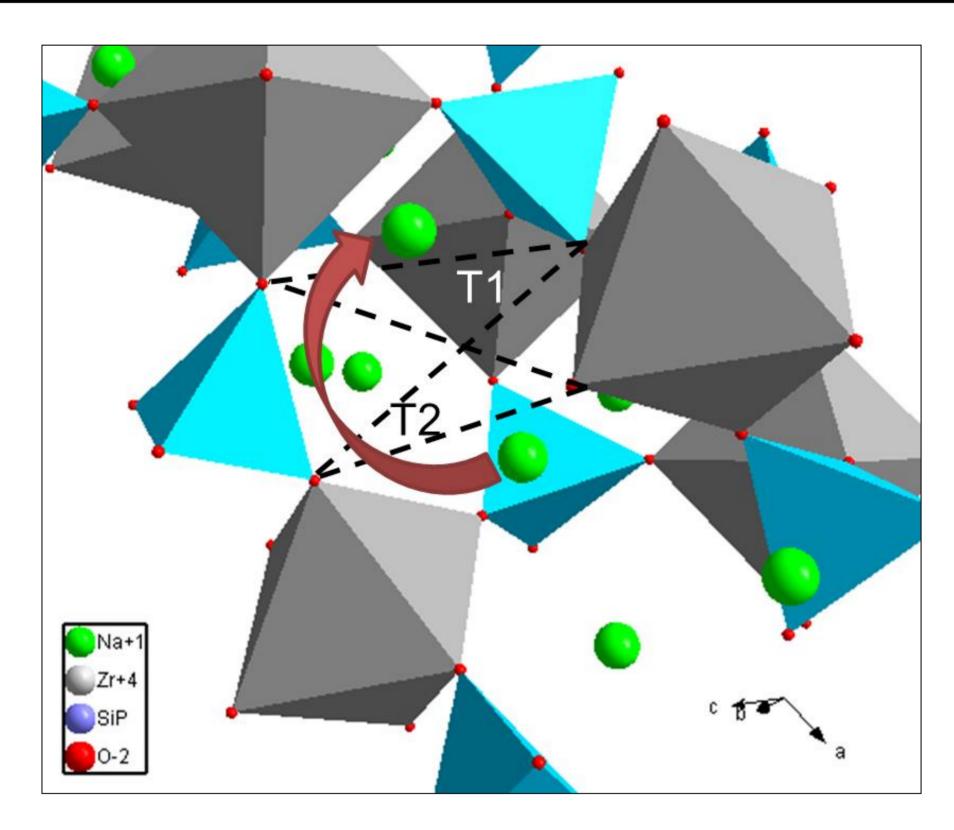


Figure 2: representation of the geometric bottleneck for the Na<sup>+</sup> conduction and the path of Na<sup>+</sup> ion hoping in Na<sub>3</sub>Zr<sub>2</sub>(SiO<sub>4</sub>)<sub>2</sub>(PO<sub>4</sub>)

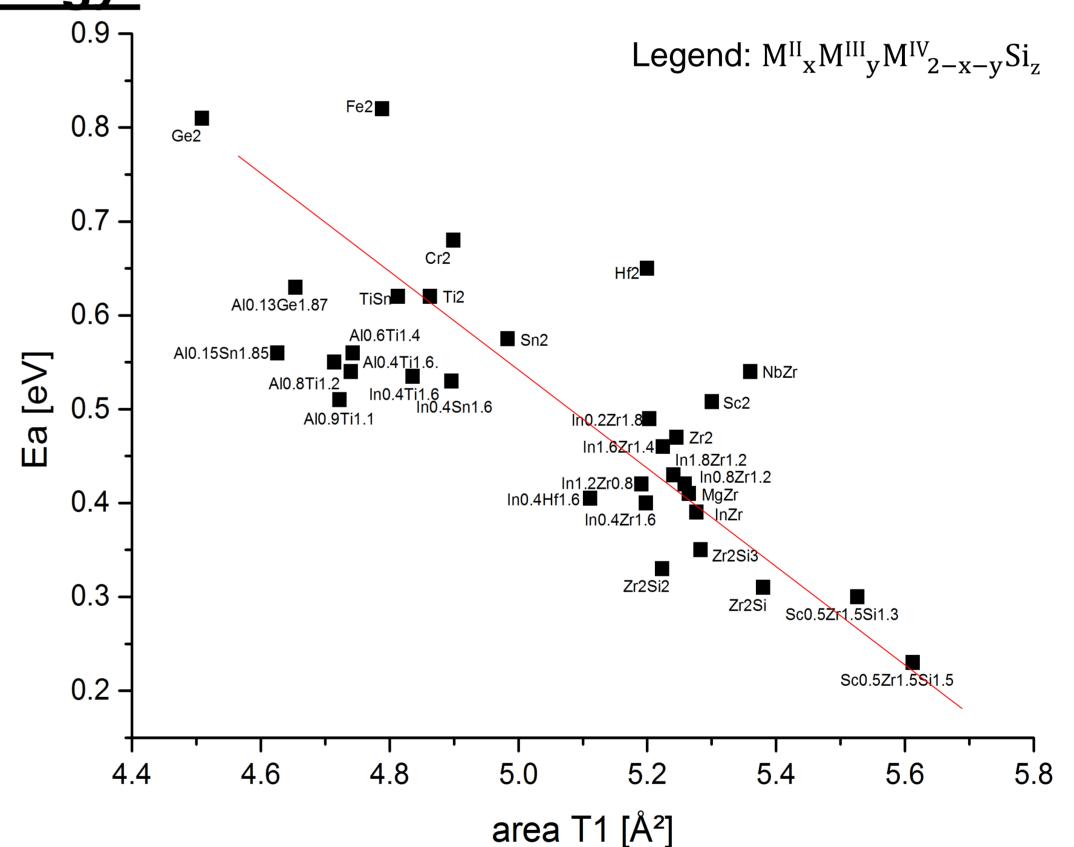


Figure 3: Influence of the area T1 on the activation energy for different NASICON materials

## Factors influencing the bottleneck for the Na<sup>+</sup> conduction:

• Size of the cations M<sup>II</sup>, M<sup>III</sup>, M<sup>IV</sup> (r<sub>eff</sub>)

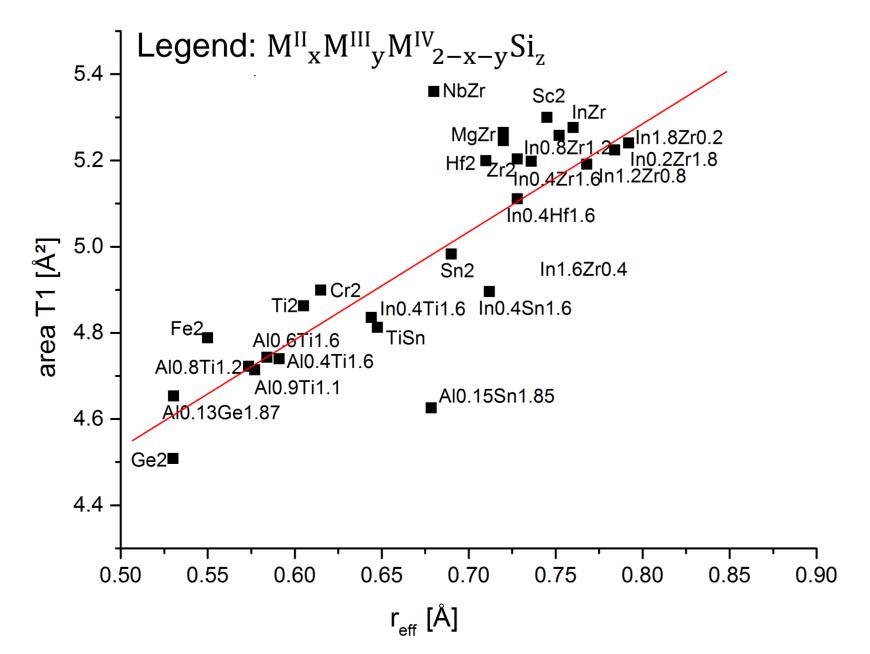


Figure 4: Influence of reff on the area T1

Presence of Si in the formula

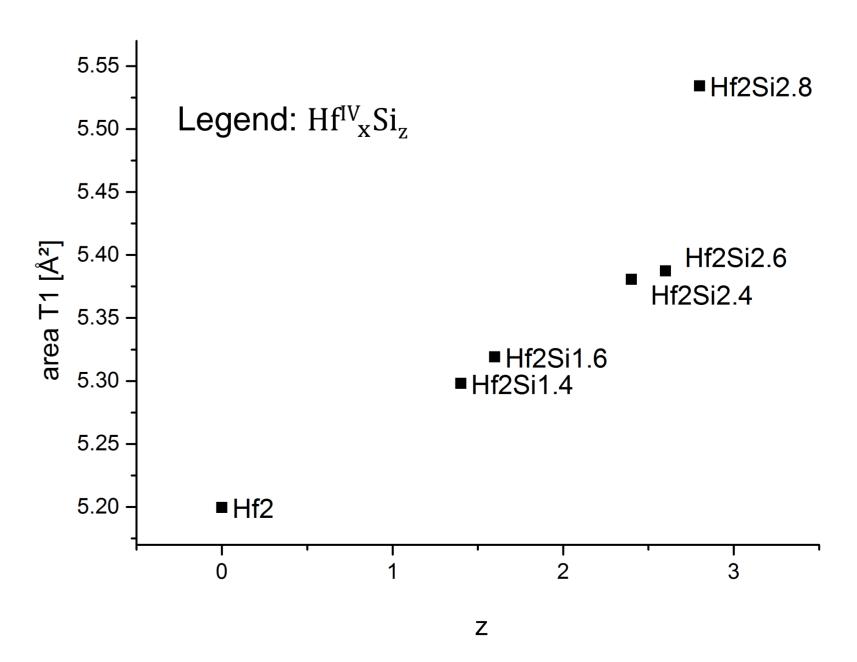


Figure 5: Influence of the amount of Si per formula on the area T1 (example of Hf-based NASICON. Vogel, E.M. et al. Solid State Ionics, 1984. **14**: p. 1-6.)

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